

2N5038  
2N5039

SILICON  
NPN POWER TRANSISTORS



TO-3 CASE



www.centrasemi.com

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N5038 and 2N5039 are silicon NPN power transistors designed for power amplifier and power oscillator applications where high current, high voltage, and fast switching speeds are required.

**MARKING: FULL PART NUMBER**

**MAXIMUM RATINGS:** ( $T_C=25^\circ\text{C}$ )

Collector-Base Voltage  
Collector-Emitter Voltage  
Collector-Emitter Voltage  
Collector-Emitter Voltage  
Emitter-Base Voltage  
Continuous Collector Current  
Peak Collector Current  
Continuous Base Current  
Power Dissipation  
Operating and Storage Junction Temperature  
Thermal Resistance

| SYMBOL         | 2N5038      | 2N5039 | UNITS              |
|----------------|-------------|--------|--------------------|
| $V_{CB0}$      | 150         | 120    | V                  |
| $V_{CEX}$      | 150         | 120    | V                  |
| $V_{CER}$      | 110         | 95     | V                  |
| $V_{CEO}$      | 90          | 75     | V                  |
| $V_{EBO}$      | 7.0         |        | V                  |
| $I_C$          | 20          |        | A                  |
| $I_{CM}$       | 30          |        | A                  |
| $I_B$          | 5.0         |        | A                  |
| $P_D$          | 140         |        | W                  |
| $T_J, T_{stg}$ | -65 to +200 |        | $^\circ\text{C}$   |
| $\theta_{JC}$  | 1.25        |        | $^\circ\text{C/W}$ |

**ELECTRICAL CHARACTERISTICS:** ( $T_C=25^\circ\text{C}$  unless otherwise noted)

| SYMBOL        | TEST CONDITIONS   | 2N5038 |     | 2N5039 |     | UNITS |
|---------------|---|--------|-----|--------|-----|-------|
|               |   | MIN    | MAX | MIN    | MAX |       |
| $I_{CEV}$     | $V_{CE}=140\text{V}, V_{BE}=1.5\text{V}$                        | -      | 50  | -      | -   | mA    |
| $I_{CEV}$     | $V_{CE}=110\text{V}, V_{BE}=1.5\text{V}$                        | -      | -   | -      | 50  | mA    |
| $I_{CEV}$     | $V_{CE}=100\text{V}, V_{BE}=1.5\text{V}, T_C=150^\circ\text{C}$ | -      | 10  | -      | -   | mA    |
| $I_{CEV}$     | $V_{CE}=85\text{V}, V_{BE}=1.5\text{V}, T_C=150^\circ\text{C}$  | -      | -   | -      | 10  | mA    |
| $I_{CEO}$     | $V_{CE}=70\text{V}$   | -      | 20  | -      | -   | mA    |
| $I_{CEO}$     | $V_{CE}=55\text{V}$   | -      | -   | -      | 20  | mA    |
| $I_{EBO}$     | $V_{EB}=5.0\text{V}$  | -      | 5.0 | -      | 15  | mA    |
| $I_{EBO}$     | $V_{EB}=7.0\text{V}$  | -      | 50  | -      | 50  | mA    |
| $BV_{CEX}$    | $I_C=200\text{mA}, V_{BE}=1.5\text{V}$                          | 150    | -   | 120    | -   | V     |
| $BV_{CER}$    | $I_C=200\text{mA}, R_{BE}\leq 50\Omega$                         | 110    | -   | 95     | -   | V     |
| $BV_{CEO}$    | $I_C=200\text{mA}$  | 90     | -   | 75     | -   | V     |
| $BV_{EBO}$    | $I_E=50\text{mA}$   | 7.0    | -   | 7.0    | -   | V     |
| $V_{CE(SAT)}$ | $I_C=12\text{A}, I_B=1.2\text{A}$                               | -      | 1.0 | -      | -   | V     |
| $V_{CE(SAT)}$ | $I_C=10\text{A}, I_B=1.0\text{A}$                               | -      | -   | -      | 1.0 | V     |
| $V_{CE(SAT)}$ | $I_C=20\text{A}, I_B=5.0\text{A}$                               | -      | 2.5 | -      | 2.5 | V     |
| $V_{BE(SAT)}$ | $I_C=20\text{A}, I_B=5.0\text{A}$                               | -      | 3.3 | -      | 3.3 | V     |
| $V_{BE(ON)}$  | $V_{CE}=5.0\text{V}, I_C=12\text{A}$                            | -      | 1.8 | -      | -   | V     |
| $V_{BE(ON)}$  | $V_{CE}=5.0\text{V}, I_C=10\text{A}$                            | -      | -   | -      | 1.8 | V     |
| $h_{FE}$      | $V_{CE}=5.0\text{V}, I_C=2.0\text{A}$                           | 50     | 250 | 30     | 250 |       |
| $h_{FE}$      | $V_{CE}=5.0\text{V}, I_C=10\text{A}$                            | -      | -   | 20     | 100 |       |
| $h_{FE}$      | $V_{CE}=5.0\text{V}, I_C=12\text{A}$                            | 20     | 100 | -      | -   |       |

R1 (17-March 2015)

**2N5038**  
**2N5039**

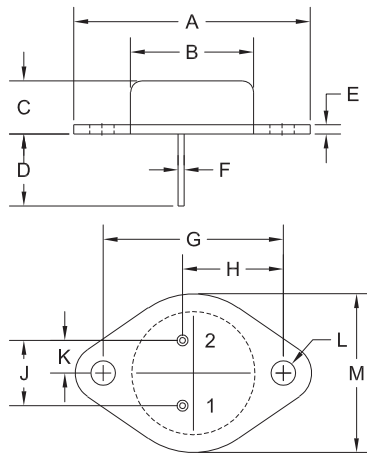
**SILICON**  
**NPN POWER TRANSISTORS**



**ELECTRICAL CHARACTERISTICS - Continued:** ( $T_C=25^\circ\text{C}$  unless otherwise noted)

| SYMBOL    | TEST CONDITIONS  | 2N5038 |     | 2N5039 |     | UNITS         |
|-----------|--|--------|-----|--------|-----|---------------|
|           |  | MIN    | MAX | MIN    | MAX |               |
| $f_T$     | $V_{CE}=10\text{V}$ , $I_C=2.0\text{A}$ , $f=5.0\text{MHz}$          | 60     | -   | 60     | -   | MHz           |
| $C_{ob}$  | $V_{CB}=10\text{V}$ , $I_E=0$ , $f=1.0\text{MHz}$                    | -      | 400 | -      | 400 | pF            |
| $I_{s/b}$ | $V_{CE}=28\text{V}$ , $t=1.0\text{s}$                                | 5.0    | -   | 5.0    | -   | A             |
| $I_{s/b}$ | $V_{CE}=45\text{V}$ , $t=1.0\text{s}$                                | 0.9    | -   | 0.9    | -   | A             |
| $t_r$     | $V_{CC}=30\text{V}$ , $I_C=12\text{A}$ , $I_{B1}=I_{B2}=1.2\text{A}$ | -      | 0.5 | -      | -   | $\mu\text{s}$ |
| $t_r$     | $V_{CC}=30\text{V}$ , $I_C=10\text{A}$ , $I_{B1}=I_{B2}=1.0\text{A}$ | -      | -   | -      | 0.5 | $\mu\text{s}$ |
| $t_s$     | $V_{CC}=30\text{V}$ , $I_C=12\text{A}$ , $I_{B1}=I_{B2}=1.2\text{A}$ | -      | 1.5 | -      | -   | $\mu\text{s}$ |
| $t_s$     | $V_{CC}=30\text{V}$ , $I_C=10\text{A}$ , $I_{B1}=I_{B2}=1.0\text{A}$ | -      | -   | -      | 1.5 | $\mu\text{s}$ |
| $t_f$     | $V_{CC}=30\text{V}$ , $I_C=12\text{A}$ , $I_{B1}=I_{B2}=1.2\text{A}$ | -      | 0.5 | -      | -   | $\mu\text{s}$ |
| $t_f$     | $V_{CC}=30\text{V}$ , $I_C=10\text{A}$ , $I_{B1}=I_{B2}=1.0\text{A}$ | -      | -   | -      | 0.5 | $\mu\text{s}$ |

**TO-3 CASE - MECHANICAL OUTLINE**



| SYMBOL  | DIMENSIONS |       |             |       |
|---------|------------|-------|-------------|-------|
|         | INCHES     |       | MILLIMETERS |       |
|         | MIN        | MAX   | MIN         | MAX   |
| A       | 1.516      | 1.573 | 38.50       | 39.96 |
| B (DIA) | 0.748      | 0.875 | 19.00       | 22.23 |
| C       | 0.250      | 0.450 | 6.35        | 11.43 |
| D       | 0.433      | 0.516 | 11.00       | 13.10 |
| E       | 0.054      | 0.065 | 1.38        | 1.65  |
| F       | 0.035      | 0.045 | 0.90        | 1.15  |
| G       | 1.177      | 1.197 | 29.90       | 30.40 |
| H       | 0.650      | 0.681 | 16.50       | 17.30 |
| J       | 0.420      | 0.440 | 10.67       | 11.18 |
| K       | 0.205      | 0.225 | 5.21        | 5.72  |
| L (DIA) | 0.151      | 0.172 | 3.84        | 4.36  |
| M       | 0.984      | 1.050 | 25.00       | 26.67 |

TO-3 (REV: R2)

R2

**LEAD CODE:**

- 1) Base
- 2) Emitter
- Case) Collector

**MARKING:**

**FULL PART NUMBER**

R1 (17-March 2015)

## OUTSTANDING SUPPORT AND SUPERIOR SERVICES



---

### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

---

### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

---

### CONTACT US

#### Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.  
145 Adams Avenue  
Hauppauge, NY 11788 USA  
Main Tel: (631) 435-1110  
Main Fax: (631) 435-1824  
Support Team Fax: (631) 435-3388  
[www.centalsemi.com](http://www.centalsemi.com)

**Worldwide Field Representatives:**  
[www.centalsemi.com/wwreps](http://www.centalsemi.com/wwreps)

**Worldwide Distributors:**  
[www.centalsemi.com/wwdistributors](http://www.centalsemi.com/wwdistributors)

---

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: [www.centalsemi.com/terms](http://www.centalsemi.com/terms)